

# TPS709 150mA、30V、1 $\mu$ A I<sub>Q</sub>、イネーブル付き電圧レギュレータ

## 1 特長

- きわめて低い I<sub>Q</sub>: 1 $\mu$ A
- 逆電流保護
- 低 I<sub>SHUTDOWN</sub>: 150nA
- 入力電圧範囲: 2.7V~30V
- 200mA のピーク出力をサポート
- 温度範囲全体で 2% の精度
- 固定出力電圧で提供:  
1.2V~6.5V
- サーマル・シャットダウン機能と過電流保護機能
- パッケージ: SOT-23-5、WSO6-6

## 2 アプリケーション

- 煙感知器と熱感知器
- サーマスタット
- モーション検出器 (PIR、uWave など)
- コードレス電動工具
- 家電機器用バッテリー・パック
- 電気メーター
- 水道メーター

## 3 概要

TPS709 シリーズのリニア・レギュレータは、消費電力が重要なアプリケーション用に設計された、静止電流が非常に低いデバイスです。高精度のバンドギャップおよびエラー・アンプにより、温度範囲全体にわたって 2% の精度が得られます。静止電流がわずか 1 $\mu$ A であるため、アイドル時の消費電力を最小限に抑える必要のある常時オンのバッテリー駆動システムに最適なソリューションです。これらのデバイスは、サーマル・シャットダウン、電流制限、逆電流保護機能により安全性が強化されています。

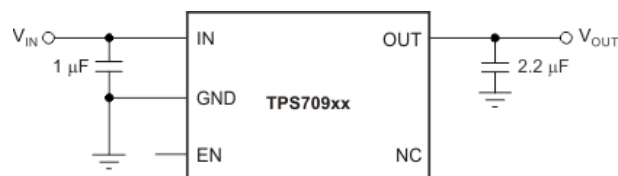
シャットダウン・モードは、EN ピンを Low にすることでイネーブルになります。このモードでのシャットダウン電流は、150nA (標準値) に低下します。

TPS709 シリーズは、WSO6-6 および SOT-23-5 パッケージで供給されます。

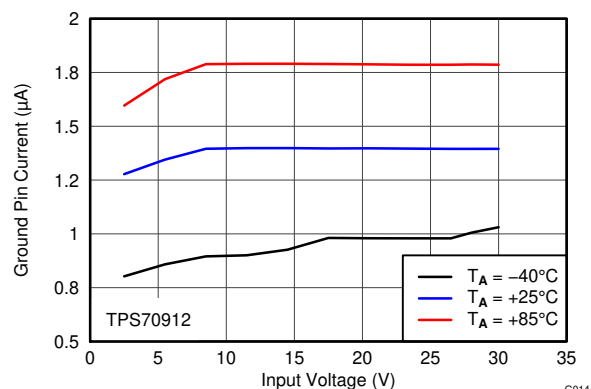
### 製品情報(1)

部品番号	パッケージ	本体サイズ (公称)
TPS709	SOT-23 (5)	2.90mm × 1.60mm
	WSO6 (6)	2.00mm × 2.00mm

- (1) 利用可能なすべてのパッケージについては、このデータシートの末尾にあるパッケージ・オプションについての付録を参照してください。



代表的なアプリケーション回路



GND 電流と V<sub>IN</sub> および温度との関係

G014



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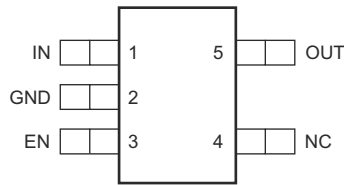
## 4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

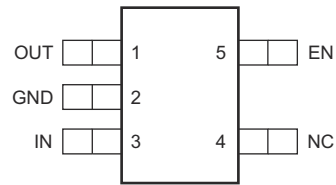
<b>Changes from Revision G (November 2015) to Revision H (July 2021)</b>	<b>Page</b>
• 文書全体にわたって表、図、相互参照の採番方法を更新.....	1
• 「アプリケーション」セクションを変更.....	1
• Changed $V_{EN(HI)}$ row (changed parameter description and added test condition) in <i>Electrical Characteristics</i> table.....	5
• Added $V_{EN(LOW)}$ row to <i>Electrical Characteristics</i> table.....	5
• Added M3 suffix information to <i>Device Nomenclature</i> table.....	17

<b>Changes from Revision F (December 2014) to Revision G (November 2015)</b>	<b>Page</b>
• Added DBV package for TPS709A to <i>Pin Configurations and Functions</i> section.....	3
• Added DBV package for TPS709B to <i>Pin Configurations and Functions</i> section.....	3
• Added TPS709A and TPS709B to Pin Functions table.....	3
• Moved operating junction temperature from <i>Electrical Characteristics</i> to <i>Recommended Operating Conditions</i> .....	4

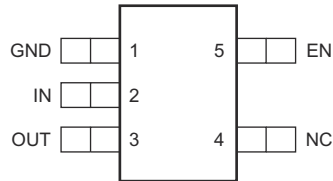
## 5 Pin Configuration and Functions



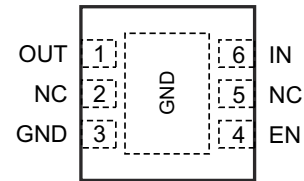
5-1. TPS709: DBV Package, 5-Pin SOT-23, Top View



5-2. TPS709A: DBV Package, 5-Pin SOT-23, Top View



5-3. TPS709B: DBV Package, 5-Pin SOT-23, Top View



5-4. DRV Package, 6-Pin WSON, Top View

表 5-1. Pin Functions

NAME	PIN				I/O	DESCRIPTION
	DRV	DBV				
	TPS709	TPS709	TPS709A	TPS709B		
EN	4	3	5	5	I	Enable pin. Drive this pin high to enable the device. Drive this pin low to put the device into low current shutdown. This pin can be left floating to enable the device. The maximum voltage must remain below 6.5 V.
GND	3	2	2	1	—	Ground
IN	6	1	3	2	I	Unregulated input to the device
NC	2, 5	4	4	4	—	No internal connection
OUT	1	5	1	3	O	Regulated output voltage. Connect a small 2.2- $\mu$ F or greater ceramic capacitor from this pin to ground to assure stability.
Thermal pad	—	—	—	—	—	The thermal pad is electrically connected to the GND node. Connect this pad to the GND plane for improved thermal performance.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

specified at  $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  (unless otherwise noted); all voltages are with respect to GND<sup>(1)</sup>

		MIN	MAX	UNIT
Voltage	$V_{IN}$	-0.3	32	V
	$V_{EN}$	-0.3	7	
	$V_{OUT}$	-0.3	7	
Maximum output current	$I_{OUT}$	Internally limited		
Output short-circuit duration		Indefinite		
Continuous total power dissipation	$P_{DISS}$	See <a href="#">Thermal Information</a>		
Operating junction temperature, $T_J$		-55	150	$^{\circ}\text{C}$
Storage temperature, $T_{stg}$		-55	150	$^{\circ}\text{C}$

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	$\pm 2000$	V
		Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	$\pm 500$	

- (1) JEDEC document JEP155 states that 2-kV HBM allows safe manufacturing with a standard ESD control process.  
(2) JEDEC document JEP157 states that 500-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$V_{IN}$	Input voltage	2.7		30	V
$V_{OUT}$	Output voltage	1.2		6.5	V
$V_{EN}$	Enable voltage	0		6.5	V
$T_J$	Operating junction temperature	-40		125	$^{\circ}\text{C}$

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS709		UNIT
		DBV	DRV	
		5 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	212.1	73.1	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	78.5	97.0	$^{\circ}\text{C}/\text{W}$
$R_{\theta JB}$	Junction-to-board thermal resistance	39.5	42.6	$^{\circ}\text{C}/\text{W}$
$\psi_{JT}$	Junction-to-top characterization parameter	2.86	2.9	$^{\circ}\text{C}/\text{W}$
$\psi_{JB}$	Junction-to-board characterization parameter	38.7	42.9	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	12.8	$^{\circ}\text{C}/\text{W}$

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics application report](#).

## 6.5 Electrical Characteristics

at ambient temperature ( $T_A$ ) =  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{IN} = V_{OUT(\text{typ})} + 1\text{ V}$  or  $2.7\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = 2\text{ V}$ , and  $C_{IN} = C_{OUT} = 2.2\text{-}\mu\text{F}$  ceramic (unless otherwise noted); typical values are at  $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{IN}$	Input voltage range		2.7		30	V
$V_{OUT}$	Output voltage range		1.2		6.5	V
$V_{OUT}$	DC output accuracy	$V_{OUT} < 3.3\text{ V}$	-2%		2%	
		$V_{OUT} \geq 3.3\text{ V}$	-1%		1%	
$\Delta V_{OUT}$	Line regulation	$(V_{OUT(\text{nom})} + 1\text{ V}, 2.7\text{ V}) \leq V_{IN} \leq 30\text{ V}$		3	10	mV
	Load regulation	$V_{IN} = V_{OUT(\text{typ})} + 1.5\text{ V}$ or $3\text{ V}$ (whichever is greater), $100\text{ }\mu\text{A} \leq I_{OUT} \leq 150\text{ mA}$		20	50	
$V_{DO}$	Dropout voltage <sup>(1) (3)</sup>	TPS70933, $I_{OUT} = 50\text{ mA}$		295	650	mV
		TPS70933, $I_{OUT} = 150\text{ mA}$		960	1400	
		TPS70950, $I_{OUT} = 50\text{ mA}$		245	500	
		TPS70950, $I_{OUT} = 150\text{ mA}$		690	1200	
		TPS70965, $I_{OUT} = 50\text{ mA}$		180	500	
		TPS70965, $I_{OUT} = 150\text{ mA}$		460	1000	
$I_{(CL)}$	Output current limit <sup>(4)</sup>	$V_{OUT} = 0.9 \times V_{OUT(\text{nom})}$	200	320	500	mA
$I_{GND}$	Ground pin current	$I_{OUT} = 0\text{ mA}$ , $V_{OUT} \leq 3.3\text{ V}$		1.3	2.05	$\mu\text{A}$
		$I_{OUT} = 0\text{ mA}$ , $V_{OUT} > 3.3\text{ V}$		1.4	2.25	
		$I_{OUT} = 150\text{ mA}$		350		
$I_{SHUTDOWN}$	Shutdown current	$V_{EN} \leq 0.4\text{ V}$ , $V_{IN} = 2.7\text{ V}$		150		nA
PSRR	Power-supply rejection ratio	$f = 10\text{ Hz}$		80		dB
		$f = 100\text{ Hz}$		62		
		$f = 1\text{ kHz}$		52		
$V_n$	Output noise voltage	BW = 10 Hz to 100 kHz, $I_{OUT} = 10\text{ mA}$ , $V_{IN} = 2.7\text{ V}$ , $V_{OUT} = 1.2\text{ V}$		190		$\mu\text{V}_{\text{RMS}}$
$t_{STR}$	Start-up time <sup>(2)</sup>	$V_{OUT(\text{nom})} \leq 3.3\text{ V}$		200	600	$\mu\text{s}$
		$V_{OUT(\text{nom})} > 3.3\text{ V}$		500	1500	
$V_{EN(\text{HI})}$	Enable pin high-level input voltage	Device enabled	0.9			V
$V_{EN(\text{LOW})}$	Enable pin low-level input voltage	Device disabled	0		0.4	V
$I_{EN}$	EN pin current	$EN = 1.0\text{ V}$ , $V_{IN} = 5.5\text{ V}$		300		nA
$I_{(\text{REV})}$	Reverse current (flowing out of IN pin)	$V_{OUT} = 3\text{ V}$ , $V_{IN} = V_{EN} = 0\text{ V}$		10		nA
	Reverse current (flowing into OUT pin)	$V_{OUT} = 3\text{ V}$ , $V_{IN} = V_{EN} = 0\text{ V}$		100		
$t_{SD}$	Thermal shutdown temperature	Shutdown, temperature increasing		158		$^{\circ}\text{C}$
		Reset, temperature decreasing		140		

(1)  $V_{DO}$  is measured with  $V_{IN} = 0.98 \times V_{OUT(\text{nom})}$ .

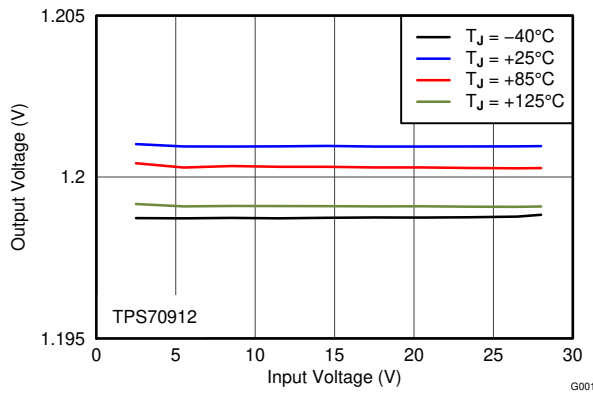
(2) Start-up time = time from EN assertion to  $0.95 \times V_{OUT(\text{nom})}$  and load =  $47\text{ }\Omega$ .

(3) Dropout is only valid when  $V_{OUT} \geq 2.8\text{ V}$  because of the minimum input voltage limits.

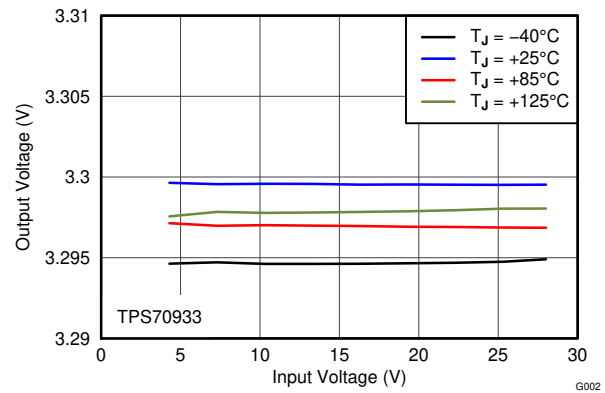
(4) Measured with  $V_{IN} = V_{OUT} + 3\text{ V}$  for  $V_{OUT} \leq 2.5\text{ V}$ . Measured with  $V_{IN} = V_{OUT} + 2.5\text{ V}$  for  $V_{OUT} > 2.5\text{ V}$ .

## 6.6 Typical Characteristics

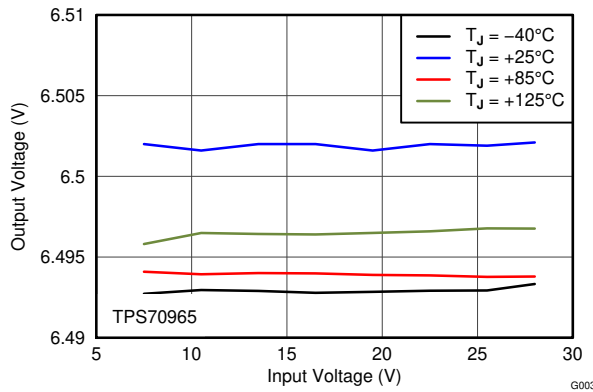
over operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $I_{\text{OUT}} = 10\text{ mA}$ ,  $V_{\text{EN}} = 2\text{ V}$ ,  $C_{\text{OUT}} = 2.2\text{ }\mu\text{F}$ , and  $V_{\text{IN}} = V_{\text{OUT(typ)}} + 1\text{ V}$  or  $2.7\text{ V}$  (whichever is greater), unless otherwise noted; typical values are at  $T_J = 25^{\circ}\text{C}$



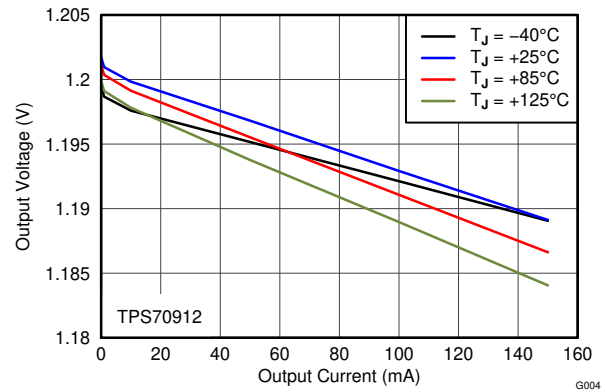
6-1. 1.2-V Line Regulation vs  $V_{\text{IN}}$  and Temperature



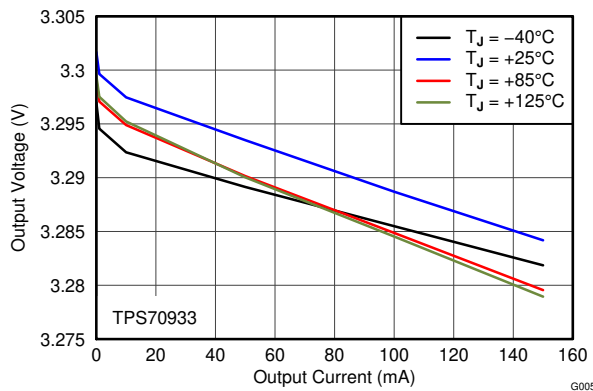
6-2. 3.3-V Line Regulation vs  $V_{\text{IN}}$  and Temperature



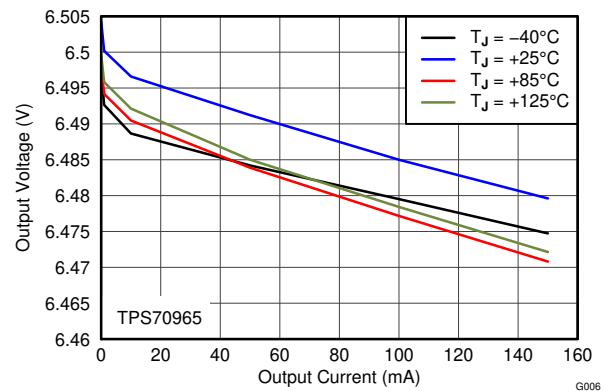
6-3. 6.5-V Line Regulation vs  $V_{\text{IN}}$  and Temperature



6-4. 1.2-V Load Regulation vs  $I_{\text{OUT}}$  and Temperature



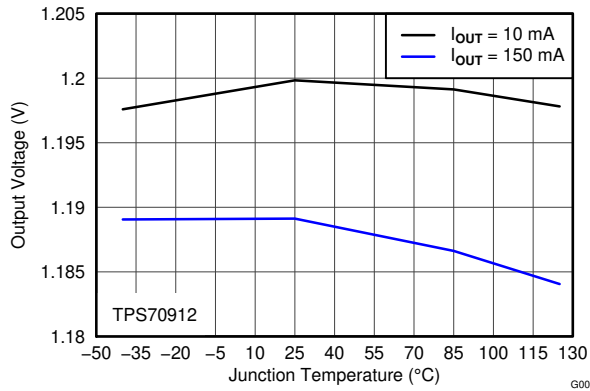
6-5. 3.3-V Load Regulation vs  $I_{\text{OUT}}$  and Temperature



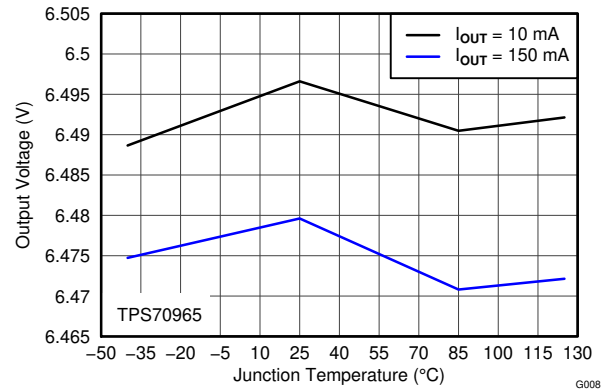
6-6. 6.5-V Load Regulation vs  $I_{\text{OUT}}$  and Temperature

## 6.6 Typical Characteristics (continued)

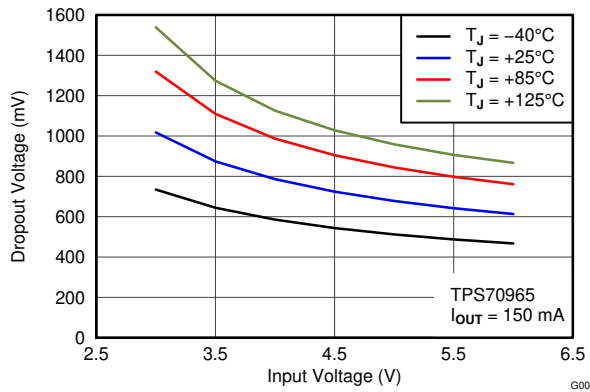
over operating temperature range ( $T_J = -40^\circ\text{C}$  to  $125^\circ\text{C}$ ),  $I_{\text{OUT}} = 10\text{ mA}$ ,  $V_{\text{EN}} = 2\text{ V}$ ,  $C_{\text{OUT}} = 2.2\text{ }\mu\text{F}$ , and  $V_{\text{IN}} = V_{\text{OUT(typ)}} + 1\text{ V}$  or  $2.7\text{ V}$  (whichever is greater), unless otherwise noted; typical values are at  $T_J = 25^\circ\text{C}$



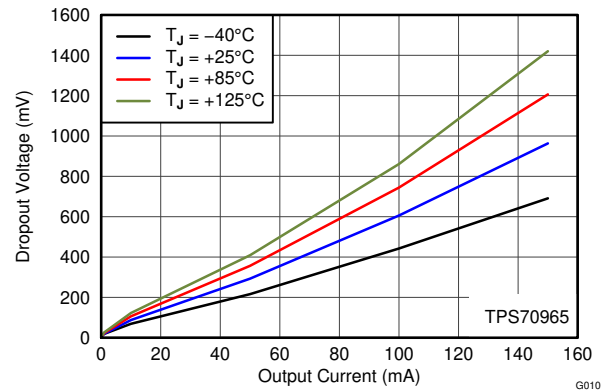
6-7.  $V_{\text{OUT}}$  vs Temperature



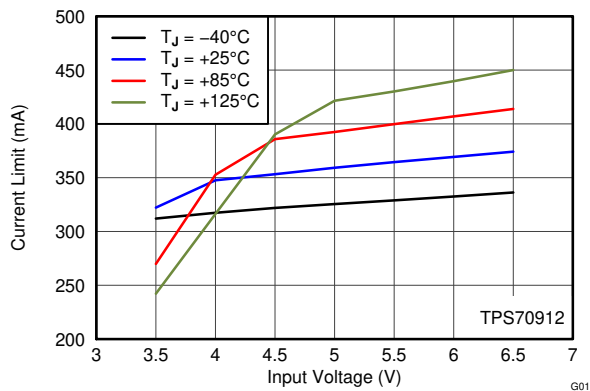
6-8.  $V_{\text{OUT}}$  vs Temperature



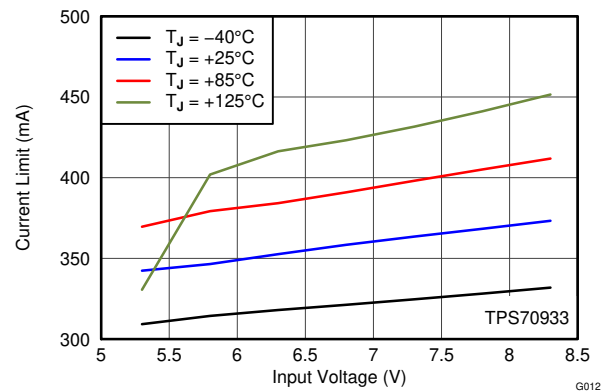
6-9. Dropout Voltage vs  $V_{\text{IN}}$  and Temperature



6-10. Dropout Voltage vs  $I_{\text{OUT}}$  and Temperature



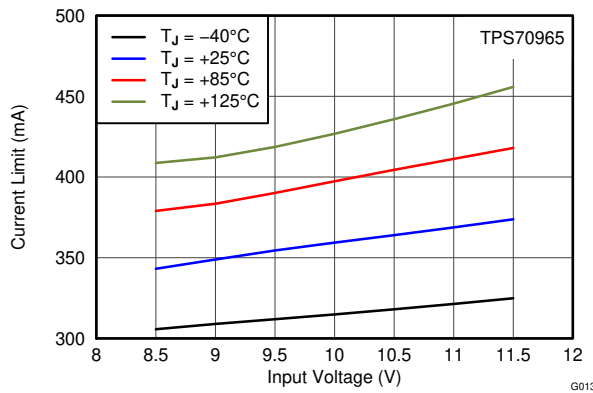
6-11. 1.2-V Current Limit vs  $V_{\text{IN}}$  and Temperature



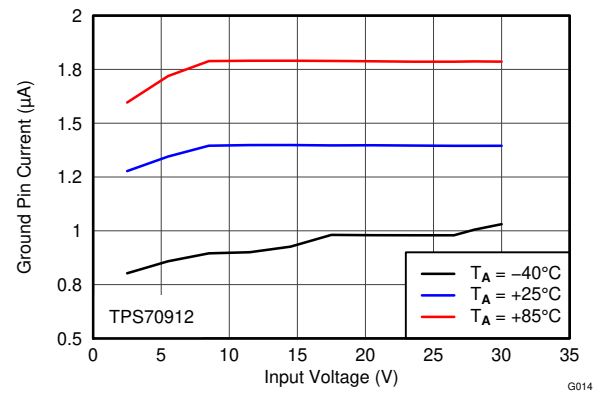
6-12. 3.3-V Current Limit vs  $V_{\text{IN}}$  and Temperature

### 6.6 Typical Characteristics (continued)

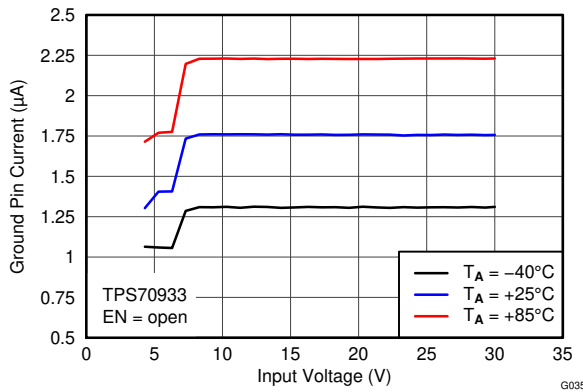
over operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $I_{OUT} = 10\text{ mA}$ ,  $V_{EN} = 2\text{ V}$ ,  $C_{OUT} = 2.2\text{ }\mu\text{F}$ , and  $V_{IN} = V_{OUT(\text{typ})} + 1\text{ V}$  or  $2.7\text{ V}$  (whichever is greater), unless otherwise noted; typical values are at  $T_J = 25^{\circ}\text{C}$



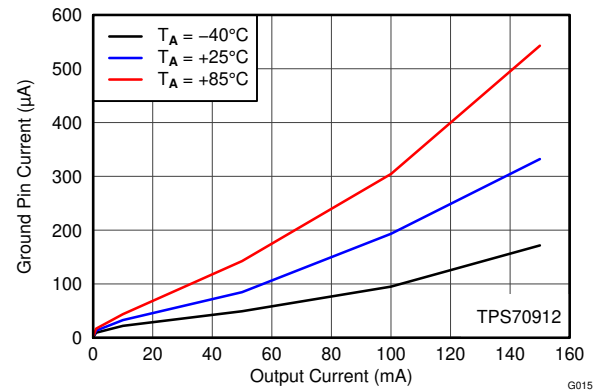
**FIG 6-13. 6.5-V Current Limit vs  $V_{IN}$  and Temperature**



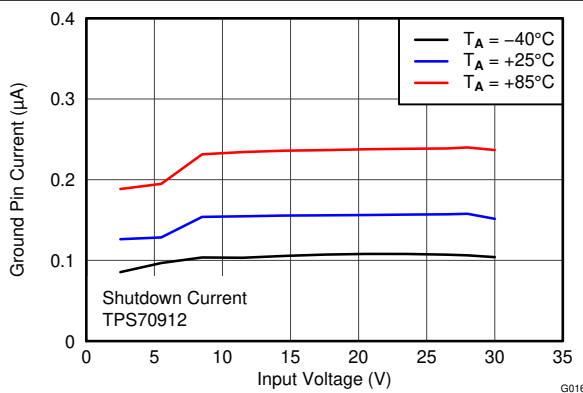
**FIG 6-14. GND Current vs  $V_{IN}$  and Temperature**



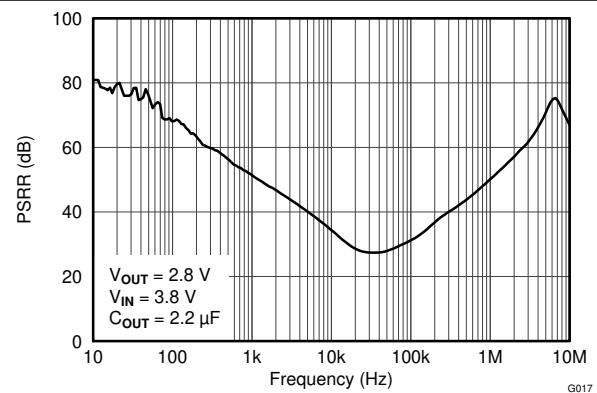
**FIG 6-15. GND Current vs  $V_{IN}$  and Temperature**



**FIG 6-16. GND Current vs  $I_{OUT}$  and Temperature**



**FIG 6-17. Shutdown Current vs  $V_{IN}$  and Temperature**



**FIG 6-18. Power-Supply Rejection Ratio vs Frequency**



## 6.6 Typical Characteristics (continued)

over operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $I_{\text{OUT}} = 10\text{ mA}$ ,  $V_{\text{EN}} = 2\text{ V}$ ,  $C_{\text{OUT}} = 2.2\text{ }\mu\text{F}$ , and  $V_{\text{IN}} = V_{\text{OUT(typ)}} + 1\text{ V}$  or  $2.7\text{ V}$  (whichever is greater), unless otherwise noted; typical values are at  $T_J = 25^{\circ}\text{C}$

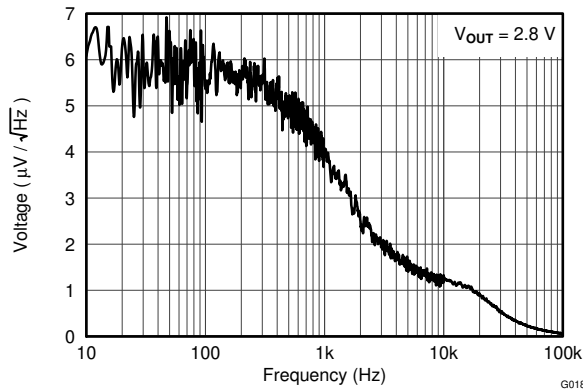


Figure 6-19. Noise

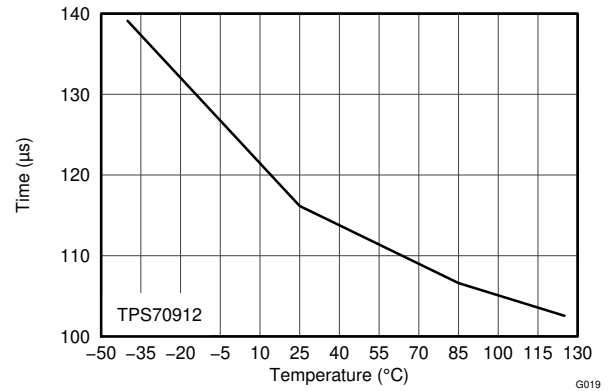


Figure 6-20. Start-Up Time vs Temperature

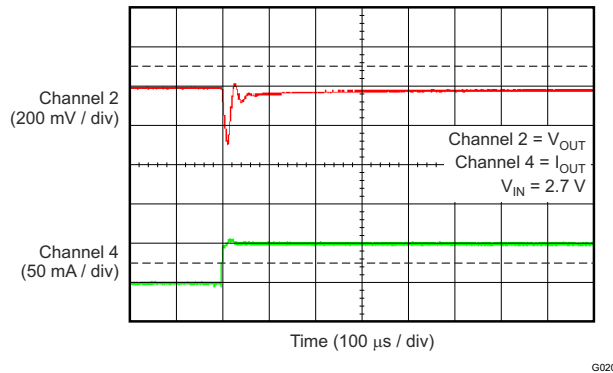


Figure 6-21. TPS70912 Load Transient (0 mA to 50 mA)

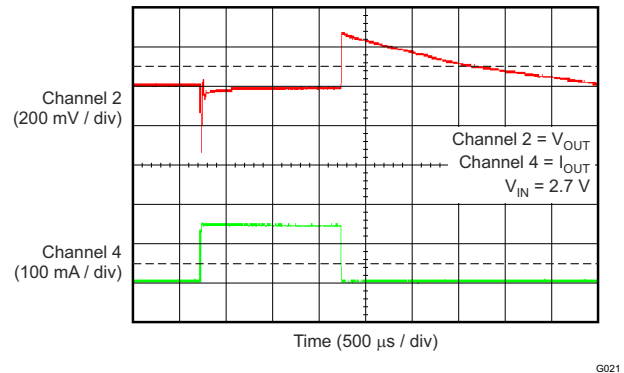


Figure 6-22. TPS70912 Load Transient (1 mA to 150 mA)

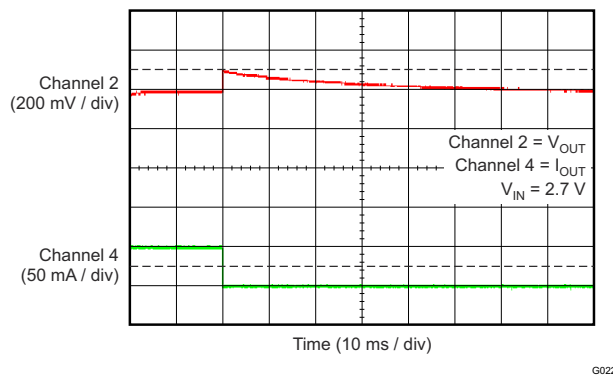


Figure 6-23. TPS70912 Load Transient (50 mA to 0 mA)

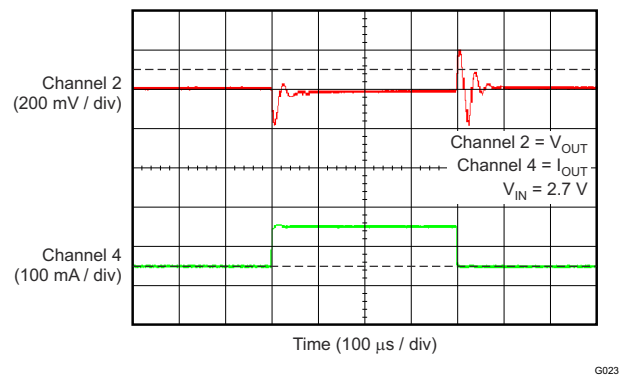
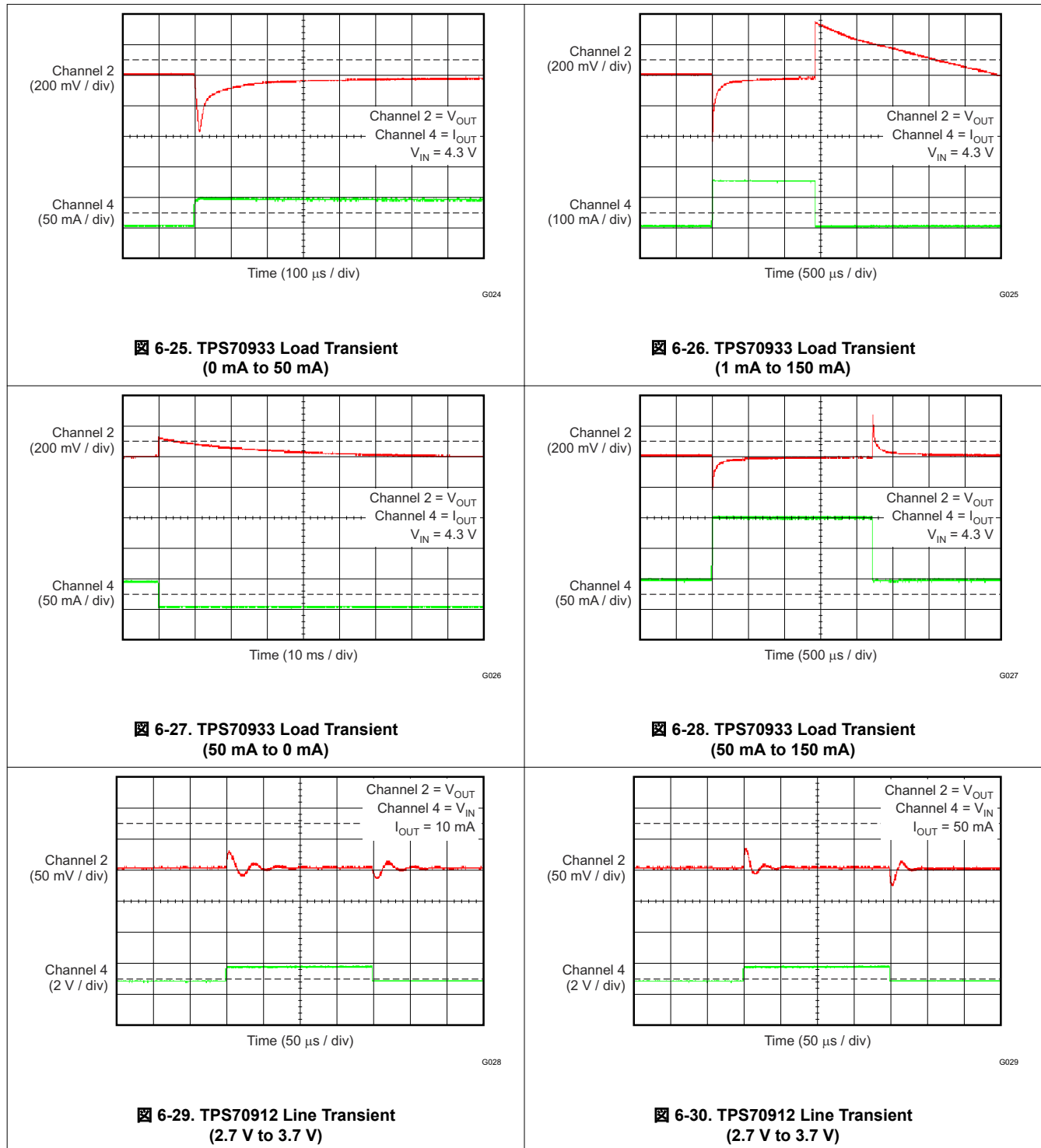


Figure 6-24. TPS70912 Load Transient (50 mA to 150 mA)

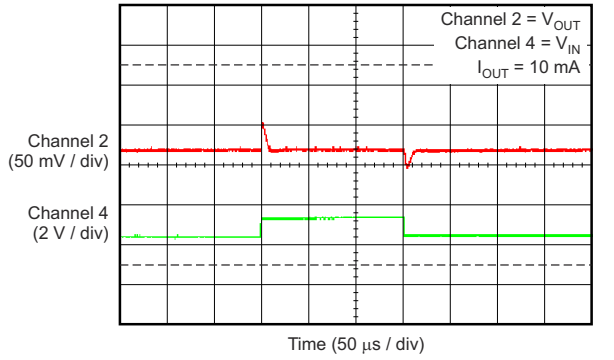
## 6.6 Typical Characteristics (continued)

over operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $I_{\text{OUT}} = 10\text{ mA}$ ,  $V_{\text{EN}} = 2\text{ V}$ ,  $C_{\text{OUT}} = 2.2\text{ }\mu\text{F}$ , and  $V_{\text{IN}} = V_{\text{OUT(typ)}} + 1\text{ V}$  or  $2.7\text{ V}$  (whichever is greater), unless otherwise noted; typical values are at  $T_J = 25^{\circ}\text{C}$

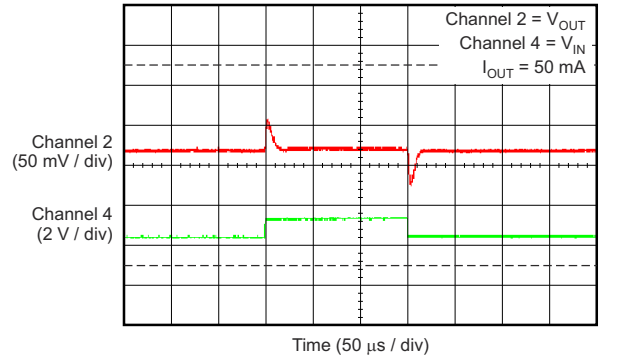


## 6.6 Typical Characteristics (continued)

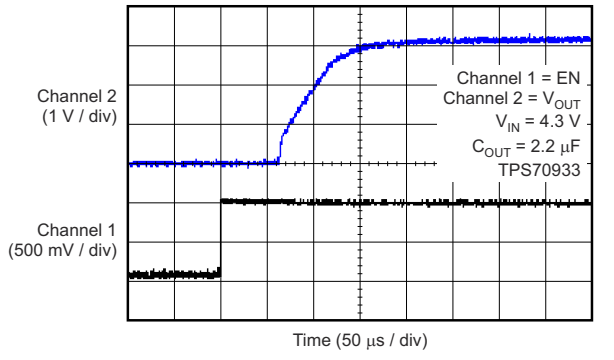
over operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $I_{OUT} = 10\text{ mA}$ ,  $V_{EN} = 2\text{ V}$ ,  $C_{OUT} = 2.2\text{ }\mu\text{F}$ , and  $V_{IN} = V_{OUT(\text{typ})} + 1\text{ V}$  or  $2.7\text{ V}$  (whichever is greater), unless otherwise noted; typical values are at  $T_J = 25^{\circ}\text{C}$



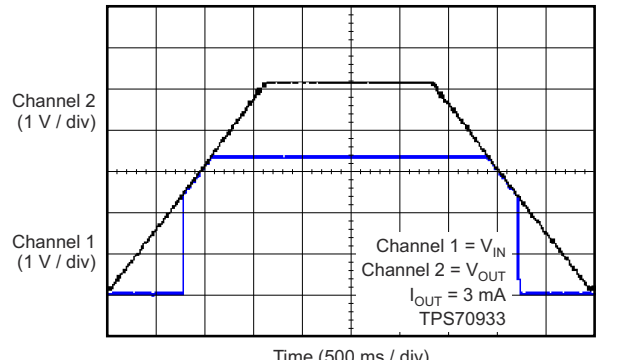
**6-31. TPS70933 Line Transient (4.3 V to 5.3 V)**



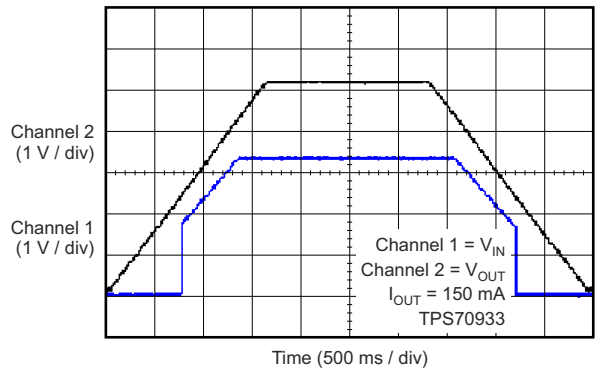
**6-32. TPS70933 Line Transient (4.3 V to 5.3 V)**



**6-33. Power-Up With Enable**



**6-34. Power-Up and Power-Down Response**



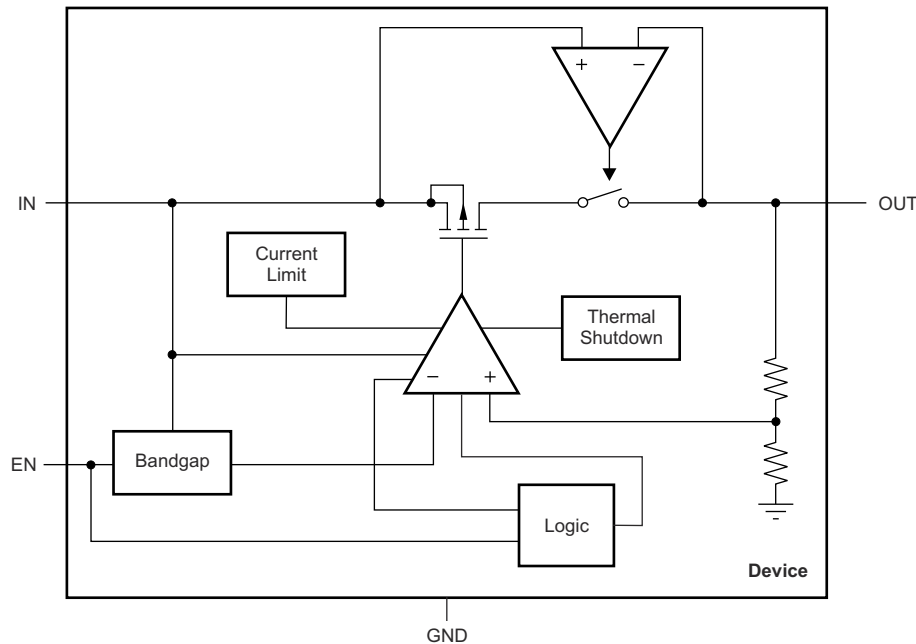
**6-35. Power-Up and Power-Down Response**

## 7 Detailed Description

### 7.1 Overview

The TPS709 series of devices are ultra-low quiescent current, low-dropout (LDO) linear regulators. The TPS709 offers reverse current protection to block any discharge current from the output into the input. The TPS709 also features current limit and thermal shutdown for reliable operation.

### 7.2 Functional Block Diagram



### 7.3 Feature Description

#### 7.3.1 Internal Current Limit

The TPS709 internal current limit helps protect the regulator during fault conditions. During current limit, the output sources a fixed amount of current that is largely independent of output voltage. In such a case, the output voltage is not regulated, and can be measured as  $(V_{OUT} = I_{LIMIT} \times R_{LOAD})$ . The PMOS pass transistor dissipates  $[(V_{IN} - V_{OUT}) \times I_{LIMIT}]$  until a thermal shutdown is triggered and the device turns off. When cool, the device is turned on by the internal thermal shutdown circuit. If the fault condition continues, the device cycles between current limit and thermal shutdown; see the [Thermal Protection](#) section for more details.

The TPS709 is characterized over the recommended operating output current range up to 150 mA. The internal current limit begins to limit the output current at a minimum of 200 mA of output current. The TPS709 continues to operate for output currents between 150 mA and 200 mA but some data sheet parameters may not be met.

#### 7.3.2 Dropout Voltage

The TPS709 use a PMOS pass transistor to achieve low dropout voltage. When  $(V_{IN} - V_{OUT})$  is less than the dropout voltage ( $V_{DO}$ ), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the  $R_{DS(ON)}$  of the PMOS pass element.  $V_{DO}$  approximately scales with the output current because the PMOS device functions like a resistor in dropout.

The ground pin current of many linear voltage regulators increases substantially when the device is operated in dropout. This increase in ground pin current while operating in dropout can be several orders of magnitude larger than when the device is not in dropout. The TPS709 employs a special control loop that limits the increase in ground pin current while operating in dropout. This functionality allows for the most efficient operation while in dropout conditions that can greatly increase battery run times.

### 7.3.3 Undervoltage Lockout (UVLO)

The TPS709 uses an undervoltage lockout (UVLO) circuit to keep the output shut off until the internal circuitry operates properly.

### 7.3.4 Reverse-Current Protection

The TPS709 has integrated reverse-current protection. Reverse-current protection prevents the flow of current from the OUT pin to the IN pin when output voltage is higher than input voltage. The reverse-current protection circuitry places the power path in high impedance when the output voltage is higher than the input voltage. This setting reduces leakage current from the output to the input to 10 nA, typical. The reverse current protection is always active regardless of the enable pin logic state or if the OUT pin voltage is greater than 1.8 V. Reverse current can flow if the output voltage is less than 1.8 V and if input voltage is less than the output voltage.

If voltage is applied to the input pin, then the maximum voltage that can be applied to the OUT pin is the lower of three times the nominal output voltage or 6.5 V. For example, if the 1.2-V output voltage version is used, then the maximum reverse bias voltage that can be applied to the OUT pin is 3.6 V. If the 5.0-V output voltage version is used, then the maximum reverse bias voltage that can be applied to the OUT pin is 6.5 V.

## 7.4 Device Functional Modes

The TPS709 has the following functional modes:

1. **Enabled:** When the enable pin (EN) goes above 0.9 V, the device is enabled. EN is pulled high by a 300-nA current source; therefore, EN can be left floating to enable the device. Do not connect EN to VIN. The EN pin is clamped by a 6.5-V Zener diode. Do not exceed the 7-V absolute maximum rating on the enable pin or excessive current flowing into the Zener clamp will destroy the device.
2. **Disabled:** When EN goes below 0.4 V, the device is disabled. During this time, OUT is high impedance and the current into IN ( $I_{\text{SHUTDOWN}}$ ) is typically 150 nA.

## 8 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The TPS709 is a series of devices that consume low quiescent current and deliver excellent line and load transient performance. This performance, combined with low noise and very good PSRR with little ( $V_{IN} - V_{OUT}$ ) headroom, makes this device ideal for RF portable applications, current limit, and thermal protection. The TPS709 is specified from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .

#### 8.1.1 Input and Output Capacitor

The TPS709 devices are stable with output capacitors with an effective capacitance of  $2.0\ \mu\text{F}$  or greater for output voltages below  $1.5\ \text{V}$ . For output voltages equal or greater than  $1.5\ \text{V}$ , the minimum effective capacitance for stability is  $1.5\ \mu\text{F}$ . The maximum capacitance for stability is  $47\ \mu\text{F}$ . The equivalent series resistance (ESR) of the output capacitor must be between  $0\ \Omega$  and  $0.2\ \Omega$  for stability.

The effective capacitance is the minimum capacitance value of a capacitor after taking into account variations resulting from tolerances, temperature, and dc bias effects. X5R- and X7R-type ceramic capacitors are recommended because these capacitors have minimal variation in value and ESR over temperature.

Although an input capacitor is not required for stability, good analog design practice is to connect a  $0.1\text{-}\mu\text{F}$  to  $2.2\text{-}\mu\text{F}$  capacitor from IN to GND. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. An input capacitor is necessary if line transients greater than  $10\ \text{V}$  in magnitude are anticipated.

#### 8.1.2 Transient Response

As with any regulator, increasing the output capacitor size reduces over- and undershoot magnitude, but increases transient response duration.

### 8.2 Typical Application

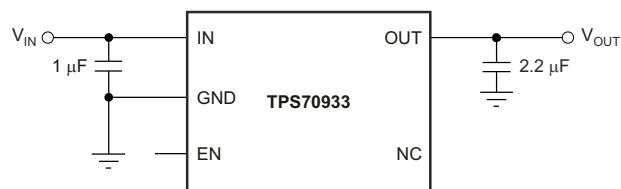


图 8-1. Wide Input, 3.3-V, Low- $I_Q$  Rail

#### 8.2.1 Design Requirements

表 8-1 summarizes the design requirements for 图 8-1.

表 8-1. Design Requirements for a Wide Input, 3.3-V, Low- $I_Q$  Rail Application

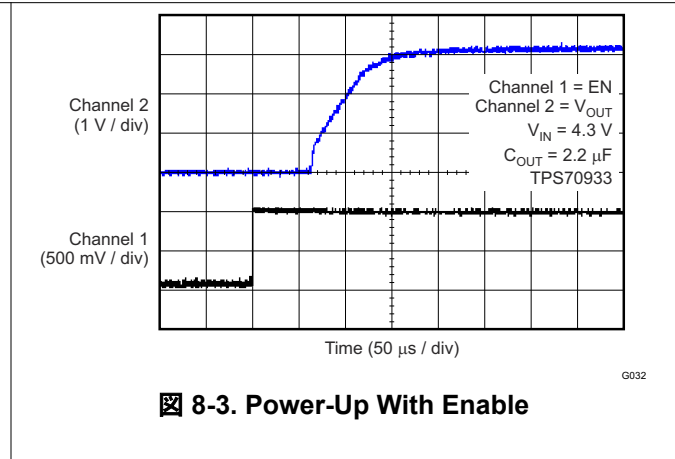
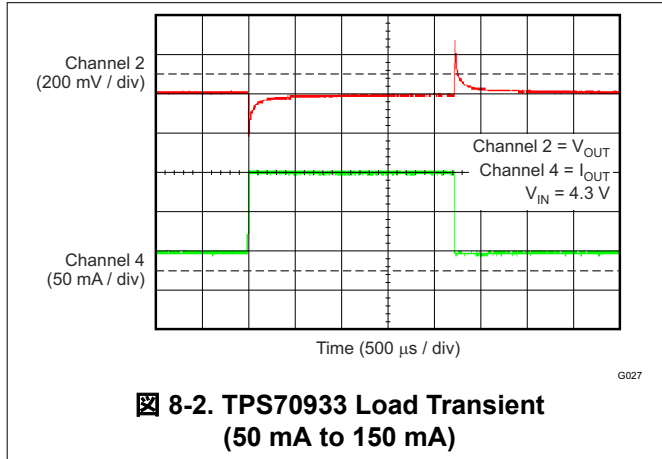
PARAMETER	DESIGN SPECIFICATION
$V_{IN}$	5 V to 20 V
$V_{OUT}$	3.3 V
$I_{(IN)}$ (no load)	< $5\ \mu\text{A}$
$I_{OUT}$ (max)	150 mA

### 8.2.2 Detailed Design Procedure

Select a 2.2- $\mu\text{F}$ , 10-V X7R output capacitor to satisfy the minimum output capacitance requirement with a 3.3-V dc bias.

Select a 1.0- $\mu\text{F}$ , 25-V X7R input capacitor to provide input noise filtering and eliminate high-frequency voltage transients.

### 8.2.3 Application Curves



## 9 Power Supply Recommendations

This device is designed to operate with an input supply range of 2.7 V to 30 V. If the input supply is noisy, additional input capacitors with low ESR can help improve output noise performance.

### 9.1 Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the printed circuit board (PCB) layout. The PCB area around the device that is free of other components moves the heat from the device to ambient air. Performance data for JEDEC low and high-K boards are given in the [Thermal Information](#) table. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves the heat sink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation ( $P_{DISS}$ ) is equal to the product of the output current and the voltage drop across the output pass element, as shown in [式 1](#):

$$P_{DISS} = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (1)$$

## 10 Layout

### 10.1 Layout Guidelines

Place input and output capacitors as close to the device pins as possible. To improve ac performance (such as PSRR, output noise, and transient response), TI recommends that the board be designed with separate ground planes for  $V_{IN}$  and  $V_{OUT}$ , with the ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor must be connected directly to the device GND pin.

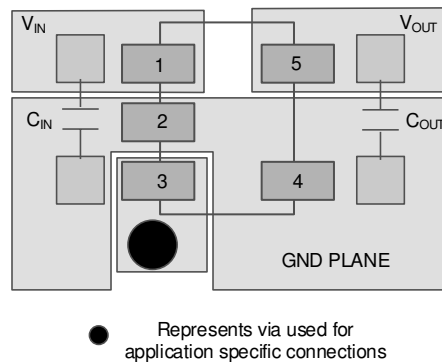
#### 10.1.1 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 165°C, allowing the device to cool. When the junction temperature cools to approximately 145°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit can cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage as a result of overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heat sink. For reliable operation, limit junction temperature to 125°C, maximum. To estimate the margin of safety in a complete design (including heat sink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection must trigger at least 35°C above the maximum expected ambient condition of the particular application. This configuration produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The TPS709 internal protection circuitry is designed to protect against overload conditions. This circuitry is not intended to replace proper heat sinking. Continuously running the TPS709 into thermal shutdown degrades device reliability.

### 10.2 Layout Example



**10-1. Layout Example for DBV Package**



## 11 Device and Documentation Support

### 11.1 Device Support

#### 11.1.1 Development Support

##### 11.1.1.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS709xx. The [TPS70933EVM-110 evaluation module](#) (and [related user guide](#)) can be requested at the Texas Instruments website through the product folders or purchased directly from the [TI eStore](#).

##### 11.1.1.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS709 is available through the product folders under *Simulation Models*.

#### 11.1.2 Device Nomenclature

表 11-1. Device Nomenclature<sup>(1)</sup>

PRODUCT	V <sub>OUT</sub>
TPS709xx(x) yyy z or TPS709xx(x) yyy zM3	<b>XX(X)</b> is the nominal output voltage. For output voltages with a resolution of 100 mV, two digits are used in the ordering number; otherwise, three digits are used (for example, 28 = 2.8 V; 125 = 1.25 V). <b>YYY</b> is the package designator. <b>Z</b> is the tape and reel quantity (R = 3000, T = 250). <b>M3</b> suffix device has same electrical specs as other devices and shares same design.

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).

### 11.2 Documentation Support

#### 11.2.1 Related Documentation

For related documentation see the following:

Texas Instruments, [TPS70933EVM-110 Evaluation Module user guide](#)

### 11.3 サポート・リソース

[TI E2E™ サポート・フォーラム](#)は、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

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### 11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

### 11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS70912DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCX	<a href="#">Samples</a>
TPS70912DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCX	<a href="#">Samples</a>
TPS70912DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCX	<a href="#">Samples</a>
TPS70912DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCX	<a href="#">Samples</a>
TPS709135DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCY	<a href="#">Samples</a>
TPS709135DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCY	<a href="#">Samples</a>
TPS70915DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIM	<a href="#">Samples</a>
TPS70915DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIM	<a href="#">Samples</a>
TPS70915DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIM	<a href="#">Samples</a>
TPS70915DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIM	<a href="#">Samples</a>
TPS70916DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCZ	<a href="#">Samples</a>
TPS70916DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SCZ	<a href="#">Samples</a>
TPS70918DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDA	<a href="#">Samples</a>
TPS70918DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDA	<a href="#">Samples</a>
TPS70918DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDA	<a href="#">Samples</a>
TPS70918DRVRM3	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDA	<a href="#">Samples</a>
TPS70918DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDA	<a href="#">Samples</a>
TPS70919DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDB	<a href="#">Samples</a>
TPS70919DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDB	<a href="#">Samples</a>
TPS70925DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDC	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS70925DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDC	<a href="#">Samples</a>
TPS70925DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDC	<a href="#">Samples</a>
TPS70925DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDC	<a href="#">Samples</a>
TPS70927DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDD	<a href="#">Samples</a>
TPS70927DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDD	<a href="#">Samples</a>
TPS70928DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDE	<a href="#">Samples</a>
TPS70928DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDE	<a href="#">Samples</a>
TPS70930DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDF	<a href="#">Samples</a>
TPS70930DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDF	<a href="#">Samples</a>
TPS70930DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDF	<a href="#">Samples</a>
TPS70930DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDF	<a href="#">Samples</a>
TPS70933DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDG	<a href="#">Samples</a>
TPS70933DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDG	<a href="#">Samples</a>
TPS70933DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDG	<a href="#">Samples</a>
TPS70933DRVRM3	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDG	<a href="#">Samples</a>
TPS70933DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDG	<a href="#">Samples</a>
TPS70936DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SEJ	<a href="#">Samples</a>
TPS70936DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SEJ	<a href="#">Samples</a>
TPS70936DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	1FV	<a href="#">Samples</a>
TPS70938DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIC	<a href="#">Samples</a>
TPS70938DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIC	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS70939DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SID	<a href="#">Samples</a>
TPS70939DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SID	<a href="#">Samples</a>
TPS70950DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDH	<a href="#">Samples</a>
TPS70950DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	SDH	<a href="#">Samples</a>
TPS70950DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDH	<a href="#">Samples</a>
TPS70950DRVRM3	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDH	<a href="#">Samples</a>
TPS70950DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SDH	<a href="#">Samples</a>
TPS70960DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIT	<a href="#">Samples</a>
TPS70960DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIT	<a href="#">Samples</a>
TPS709A30DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11RF	<a href="#">Samples</a>
TPS709A30DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11RF	<a href="#">Samples</a>
TPS709A33DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	11SF	<a href="#">Samples</a>
TPS709A33DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	11SF	<a href="#">Samples</a>
TPS709B33DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13C7	<a href="#">Samples</a>
TPS709B33DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13C7	<a href="#">Samples</a>
TPS709B345DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1XSW	<a href="#">Samples</a>
TPS709B50DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13D7	<a href="#">Samples</a>
TPS709B50DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	13D7	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of  $\leq 1000$ ppm threshold. Antimony trioxide based flame retardants must also meet the  $\leq 1000$ ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPS709 :**

- Automotive : [TPS709-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS70912DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS70912DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70912DRVR	WSO	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70912DRVT	WSO	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS709135DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709135DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70915DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70915DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70915DRVR	WSO	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS70915DRVT	WSO	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70915DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS70915DRVT	WSO	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70916DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70916DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70918DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70918DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS70918DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70918DRVRM3	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70918DRVT	WSON	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70919DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70919DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70919DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70919DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70925DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70925DBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS70925DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70925DRVT	WSON	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70927DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70927DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70928DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70928DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70930DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70930DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70930DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70930DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70930DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70930DRVT	WSON	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70933DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70933DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70933DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70933DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70933DRVRM3	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70933DRVT	WSON	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70936DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70936DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70936DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70936DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70936DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70938DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70938DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70939DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70939DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70950DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70950DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70950DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS70950DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70950DRVRM3	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS70950DRVT	WSON	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS70960DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS70960DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709A30DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709A30DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709A33DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709A33DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709B33DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709B33DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709B345DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709B50DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS709B50DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS70912DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70912DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70912DRVR	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70912DRVT	WSON	DRV	6	250	182.0	182.0	20.0
TPS709135DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS709135DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70915DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70915DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70915DRVR	WSON	DRV	6	3000	200.0	183.0	25.0
TPS70915DRVR	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70915DRVT	WSON	DRV	6	250	200.0	183.0	25.0
TPS70915DRVT	WSON	DRV	6	250	182.0	182.0	20.0
TPS70916DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70916DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70918DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70918DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70918DRVR	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70918DRVRM3	WSON	DRV	6	3000	182.0	182.0	20.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS70918DRV	WSON	DRV	6	250	182.0	182.0	20.0
TPS70919DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70919DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70919DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70919DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70925DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70925DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70925DRV	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70925DRV	WSON	DRV	6	250	182.0	182.0	20.0
TPS70927DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70927DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70928DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70928DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70930DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70930DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70930DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70930DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70930DRV	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70930DRV	WSON	DRV	6	250	182.0	182.0	20.0
TPS70933DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70933DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70933DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70933DRV	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70933DRV	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70933DRV	WSON	DRV	6	250	182.0	182.0	20.0
TPS70936DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70936DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70936DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70936DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70936DRV	WSON	DRV	6	3000	210.0	185.0	35.0
TPS70938DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70938DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70939DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70939DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS70950DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS70950DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70950DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS70950DRV	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70950DRV	WSON	DRV	6	3000	182.0	182.0	20.0
TPS70950DRV	WSON	DRV	6	250	182.0	182.0	20.0
TPS70960DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS70960DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS709A30DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS709A30DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS709A33DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS709A33DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS709B33DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS709B33DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS709B345DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS709B50DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS709B50DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0

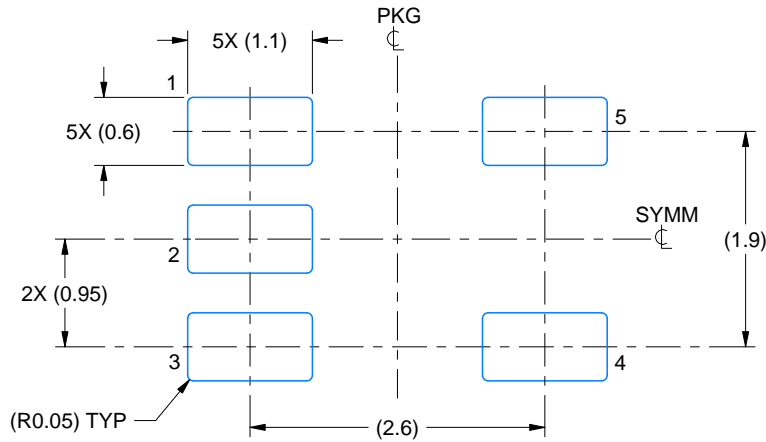


# EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## GENERIC PACKAGE VIEW

DRV 6

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4206925/F





4222173/B 04/2018

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

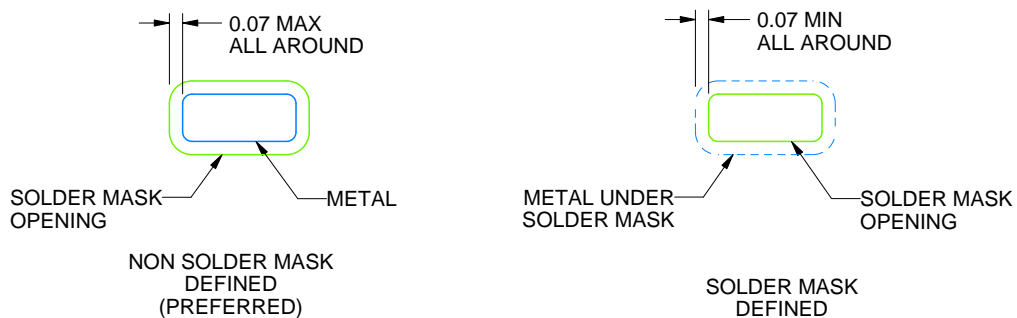
DRV0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:25X



SOLDER MASK DETAILS

4222173/B 04/2018

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

# EXAMPLE STENCIL DESIGN

DRV0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7  
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:30X

4222173/B 04/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



4225563/A 12/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

DRV0006D

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:25X



SOLDER MASK DETAILS

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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

# EXAMPLE STENCIL DESIGN

DRV0006D

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7  
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:30X

4225563/A 12/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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